2SB0946 (2SB946)

Silicon PNP epitaxial planar type

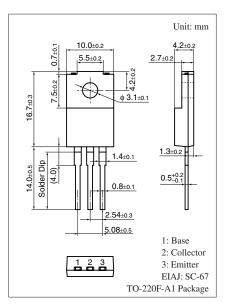
For power switching Complementary to 2SD1271

Features

- \bullet Low collector-emitter saturation voltage $V_{CE(sat)}$
- \bullet Satisfactory linearity of forward current transfer ratio h_{FE}
- \bullet Large collector current I_{C}
- · Full-pack package which can be installed to the heat sink with one screw

Absolute Maximum Ratings $T_C = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Collector-base voltage (En	V _{CBO}	-130	V	
Collector-emitter voltage	V _{CEO}	-80	V	
Emitter-base voltage (Col	V _{EBO}	-7	V	
Collector current	I _C	-7	А	
Peak collector current	I _{CP}	-15	А	
Collector power	P _C	40	W	
dissipation	$T_a = 25^{\circ}C$		2	
Junction temperature	Tj	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	



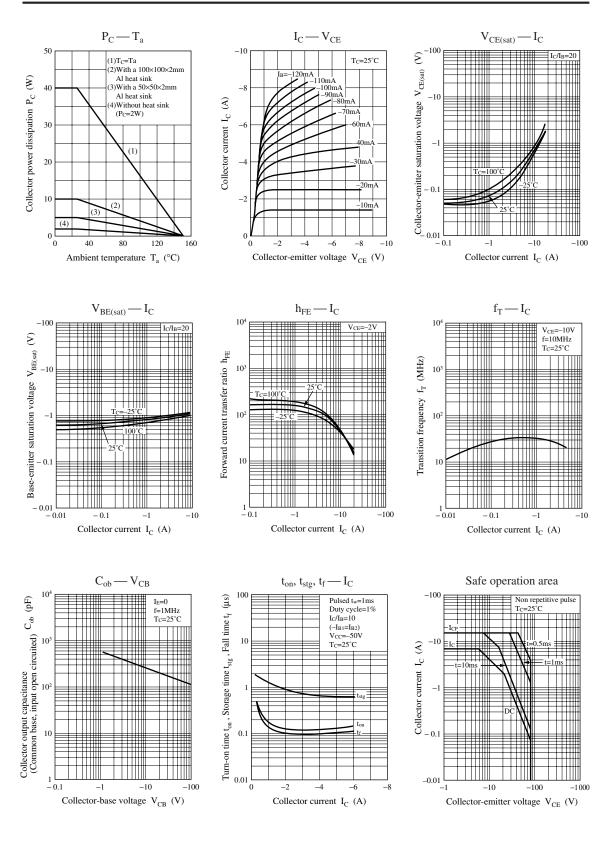
Electrical Characteristics $T_C = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = -10 \text{ mA}, I_{\rm B} = 0$	-80			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = -100 \text{ V}, I_E = 0$			-10	μΑ
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{EB} = -5 V, I_C = 0$			-50	μΑ
Forward current transfer ratio	h _{FE1}	$V_{CE} = -2 V, I_C = -0.1 A$	45			_
	h _{FE2} *	$V_{CE} = -2 V, I_C = -3 A$	60		260	
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = -5 A, I_B = -0.25 A$			- 0.5	V
Base-emitter saturation voltage	V _{BE(sat)}	$I_{C} = -5 A, I_{B} = -0.25 A$			-1.5	V
Transition frequency	f _T	$V_{CE} = -10 \text{ V}, I_C = -0.5 \text{ A}, f = 10 \text{ MHz}$		30		MHz
Turn-on time	t _{on}	$I_C = -3 A$, $I_{B1} = -0.3 A$, $I_{B2} = 0.3 A$		0.5		μs
Storage time	t _{stg}	$V_{CC} = -50 \text{ V}$		1.5		μs
Fall time	t _f			0.1		μs

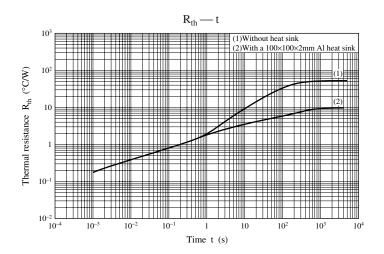
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors. 2. *: Rank classification

Rank	R	Q	Р
h _{FE2}	60 to 120	90 to 180	130 to 260

Note) The part number in the parenthesis shows conventional part number.



Panasonic



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